NSN 5962-01-372-6878

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View Online at https://aerobasegroup.com/nsn/5962-01-372-6878

Body Length:

- 1.060 inches
- **Body Width:**
- 0.200 inches

Body Height:

0.310 inches

Maximum Power Dissipation Rating:

1.2 watts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

7p blk 2 dcn, e/i fscm 49956

Features Provided:

Programmable

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Bipolar metal-oxide semiconductor

Input Circuit Pattern:

16 input

Case Outline Source And Designator:

D-8 mil-m-38510

Current Rating Per Characteristic:

12.00 milliamperes average forward current averaged over a full 60-hz cycle not applicable

Terminal Surface Treatment:

Solder

Product Name:

Microcircuit, memory, 16-input 4-output registered and-or gate array

Voltage Rating And Type Per Characteristic:

5.0 volts power source

Memory Device Type:

Pal

Hybrid Technology Type:

Monolithic

Test Data Document:

81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). And 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

20 printed airquit

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Specification Data:

67268-5962-85155 government standard

Specification Or Standard:

16 type and r case and a finish

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0